Linear Regulator - High Accuracy, Low Dropout, Power Good Function

500 mA

The NCV8537 is a high performance low dropout linear voltage regulator. Based on the popular NCV8535, the device retains all the best features of its predecessor which includes high accuracy, excellent stability, low noise performance and reverse bias protection but now includes a Power Good output signal to enable monitoring of the supply system. The device is available with fixed or adjustable outputs and is packaged in a 10 pin 3x3 mm DFN package.

Features

- High Accuracy Output Over Line and Load Variances (±0.9% at 25°C)
- Operating Temperature Range: -40°C to 125°C
- Power Good Output to Indicate the Regulator is Within Specified Limits
- Stable Output with Low Value Capacitors of any type and with no Minimum Load Current Requirement
- Incorporates Current Limiting and Reverse Bias Protection
- Thermal Shutdown Protection
- Low Dropout Voltage at Full Load (340 mV typ at $V_0 = 3.3 \text{ V}$)
- Low Noise (33 μ Vrms w/ 10 nF C_{nr} and 52 μ Vrms w/out C_{nr})
- Low Shutdown Current (< 1 mA)
- Reverse Bias Protected
- 2.9 V to 12 V Supply Range
- Available in 1.8 V, 2.5 V, 3.3 V, 5.0 V and Adjustable Output Voltages
- NCV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable
- These are Pb-Free Devices

Applications

- Networking Systems, DSL/Cable Modems
- Audio Systems for Automotive Applications
- Navigation Systems
- Satellite Receivers



ON Semiconductor®

www.onsemi.com



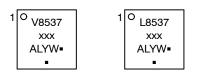
DFN10 CASE 485C

DFNW10 CASE 507AM

PIN CONFIGURATION



MARKING DIAGRAM





(Note: Microdot may be in either location)

ORDERING INFORMATION

See detailed ordering, marking and shipping information in the package dimensions section on page 15 of this data sheet.

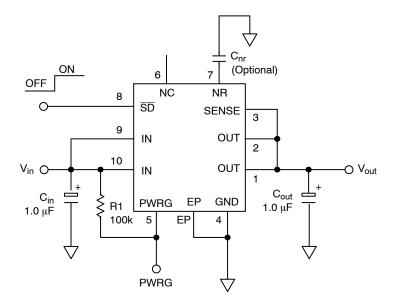


Figure 1. Typical Fixed Version Application Schematic

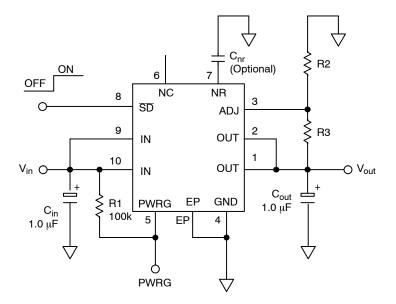
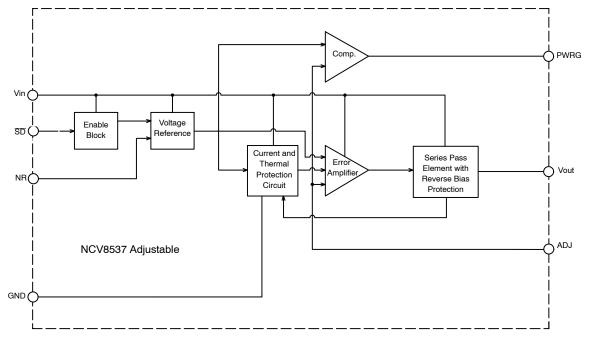


Figure 2. Typical Adjustable Version Application Schematic





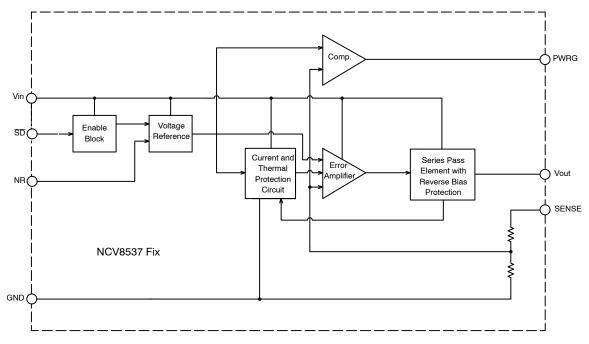


Figure 4. Block Diagram, Fixed Output Version

PIN FUNCTION DESCRIPTION

Pin No.	Pin Name	Description
1, 2	V _{out}	Regulated output voltage. Bypass to ground with $C_{out} \geq 1.0 \ \mu F$
3	SENSE/ADJ	For output voltage sensing, connect to Pins 1 and 2.at Fixed output Voltage version Adjustable pin at Adjustable output version
4	GND	Power Supply Ground
5	PWRG	Power Good
6	NC	Not Connected
7	NR	Noise Reduction Pin. This is an optional pin used to further reduce noise.
8	SD	Shutdown pin. When not in use, this pin should be connected to the input pin.
9, 10	V _{in}	Power Supply Input Voltage
EPAD	EPAD	Exposed thermal pad should be connected to ground.

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Input Voltage	V _{in}	-0.3 to +16	V
Output Voltage	V _{out}	–0.3 to V _{in} +0.3 or 10 V*	V
PWRG Pin Voltage	V _{PWRG}	–0.3 to +16	V
Shutdown Pin Voltage	V _{sh}	–0.3 to +16	V
Junction Temperature Range	Т _Ј	-40 to +150	°C
Storage Temperature Range	T _{stg}	–50 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

NOTE: This device series contains ESD protection and exceeds the following tests:

Human Body Model (HBM) tested per AEC-Q100-002 (EIA/JESD22-A114)

Machine Model (MM) tested per AEC-Q100-003 (EIA/JESD22-A115)

Charged Device Model (CDM) tested per EIA/JESD22-C101.

*Which ever is less. Reverse bias protection feature valid only if $(V_{out} - V_{in}) \le 7 V$.

THERMAL CHARACTERISTICS

	Test Conditions (Typical Value)				
Characteristic	Min Pad Board (Note 1)	1" Pad Board (Note 1)	Unit		
Junction-to-Air, θJA	215	66	°C/W		
Junction-to-Pin, J-L4	58	18	°C/W		

1. As mounted on a 35 x 35 x 1.5 mm FR4 Substrate, with a single layer of a specified copper area of 2 oz (0.07 mm thick) copper traces and heat spreading area. JEDEC 51 specifications for a low and high conductivity test board recommend a 2 oz copper thickness. Test conditions are under natural convection or zero air flow.

ELECTRICAL CHARACTERISTICS - 1.8 V

(V_{out} = 1.8 V typical, V_{in} = 2.9 V, $T_A = -40^{\circ}C$ to +125°C, unless otherwise noted, Note 2)

Characteristic	Symbol	Min	Тур	Max	Unit
Output Voltage (Accuracy) V_{in} = 2.9 V to 5.8 V, I _{load} = 0.1 mA to 500 mA, T _A = 25°C	V _{out}	-0.9% 1.783	1.8	+0.9% 1.817	V
Output Voltage (Accuracy) V_{in} = 2.9 V to 5.8 V, I _{load} = 0.1 mA to 500 mA, T _A = 0°C to +85°C	V _{out}	–1.4% 1.774	1.8	+1.4% 1.826	V
Output Voltage (Accuracy) V_{in} = 2.9 V to 5.8 V, I _{load} = 0.1 mA to 500 mA, T _A = -40°C to +125°C	V _{out}	-1.5% 1.773	1.8	+1.5% 1.827	V
Minimum Input Voltage	V _{inmin}		2.9		V
Line Regulation $V_{in} = 2.9 \text{ V to } 12 \text{ V}, \text{ I}_{load} = 0.1 \text{ mA}$	Line _{Reg}		0.04		mV/V
Load Regulation V _{in} = 2.9 V, I _{load} = 0.1 mA to 500 mA	Load _{Reg}		0.04		mV/mA
Dropout Voltage (See Figure 9) I _{load} = 500 mA (Notes 3, 4) I _{load} = 300 mA (Notes 3, 4) I _{load} = 50 mA (Notes 3, 4)	V _{DO}		620 230 95		mV
Peak Output Current (See Figures 14 and 17)	I _{pk}	500	700	830	mA
Short Output Current (See Figure 14) V_{in} < 7 V, T_A = 25°C	I _{sc}			900	mA
Thermal Shutdown / Hysteresis	TJ		160/10		°C
Ground Current In Regulation $I_{load} = 500 \text{ mA} \text{ (Note 3)}$ $I_{load} = 300 \text{ mA} \text{ (Note 3)}$ $I_{load} = 50 \text{ mA}$ $I_{load} = 0.1 \text{ mA}$	IGND		9.0 4.6 0.8 -	14 7.5 2.5 220	mA μA
In Dropout V _{in} = 2.2 V, I _{load} = 0.1 mA				500	μA
In Shutdown V _{SD} = 0 V	I _{GNDsh}			1.0	μΑ
Output Noise $C_{nr} = 0 \text{ nF}$, $I_{load} = 500 \text{ mA}$, f = 10 Hz to 100 kHz, $C_{out} = 10 \mu\text{F}$ $C_{nr} = 10 \text{ nF}$, $I_{load} = 500 \text{ mA}$, f = 10 Hz to 100 kHz, $C_{out} = 10 \mu\text{F}$	V _{noise}		52 33		μVrms μVrms
Power Good Voltage Low Threshold Hysteresis High Threshold	V _{elft}	93	95 2 97	99	% of V _{out}
Power Good Pin Voltage Saturation (I _{ef} – 1.0 mA)	V _{efdo}		200		mV
Power Good Pin Leakage	I _{efleak}		1.0		μΑ
Power Good Blanking Time (Note 7)	t _{ef}		50		μs
Shutdown Threshold Voltage ON Threshold Voltage OFF	V _{SD}	2.0		0.4	V V
SD Input Current, V_{SD} = 0 V to 0.4 V or V_{SD} = 2.0 V to V_{in}	I _{SD}		0.07	1.0	μΑ
Output Current In Shutdown Mode, V _{out} = 0 V	I _{OSD}		0.07	1.0	μΑ
Reverse Bias Protection, Current Flowing from the Output Pin to GND (V _{in} = 0 V, V _{out forced} = 1.8 V)	I _{OUTR}		10		μΑ

Performance guaranteed over the operating temperature range by design and/or characterization, production tested at T_J = T_A = 25°C. Low duty cycle pulse techniques are used during testing to maintain the junction temperature as close to ambient as possible.
T_A must be greater than 0°C.
Maximum dropout voltage is limited by minimum input voltage V_{in} = 2.9 V recommended for guaranteed operation.

ELECTRICAL CHARACTERISTICS - 2.5 V

(V_{out} = 2.5 V typical, V_{in} = 2.9 V, $T_A = -40^{\circ}C$ to +125°C, unless otherwise noted, Note 5)

Characteristic	Symbol	Min	Тур	Max	Unit
Output Voltage (Accuracy) V_{in} = 2.9 V to 6.5 V, I _{load} = 0.1 mA to 500 mA, T _A = 25°C	V _{out}	-0.9% 2.477	2.5	+0.9% 2.523	V
Output Voltage (Accuracy) V_{in} = 2.9 V to 6.5 V, I _{load} = 0.1 mA to 500 mA, T _A = 0°C to +85°C	V _{out}	-1.4% 2.465	2.5	+1.4% 2.535	V
Output Voltage (Accuracy) V_{in} = 2.9 V to 6.5 V, I _{load} = 0.1 mA to 500 mA, T _A = -40°C to +125°C	V _{out}	-1.5% 2.462	2.5	+1.5% 2.538	V
Minimum Input Voltage	V _{inmin}		2.9		V
Line Regulation $V_{in} = 2.9 \text{ V to } 12 \text{ V}, \text{ I}_{load} = 0.1 \text{ mA}$	Line _{Reg}		0.04		mV/V
Load Regulation V _{in} = 2.9 V, I _{load} = 0.1 mA to 500 mA	Load _{Reg}		0.04		mV/mA
Dropout Voltage (See Figure 10) $I_{load} = 500 \text{ mA}$ (Note 6) $I_{load} = 300 \text{ mA}$ (Note 6) $I_{load} = 50 \text{ mA}$ $I_{load} = 0.1 \text{ mA}$	V _{DO}		340 230 110 10		mV
Peak Output Current (See Figures 14 and 18)	I _{pk}	500	700	800	mA
Short Output Current (See Figure 14) V_{in} < 7 V, T_A = 25°C	I _{sc}			900	mA
Thermal Shutdown / Hysteresis	TJ		160/10		°C
Ground Current In Regulation $I_{load} = 500 \text{ mA} \text{ (Note 6)}$ $I_{load} = 300 \text{ mA} \text{ (Note 6)}$ $I_{load} = 50 \text{ mA}$ $I_{load} = 0.1 \text{ mA}$	I _{GND}		9.0 4.6 0.8 -	14 7.5 2.5 220	mA μA
In Dropout V _{in} = 2.4 V, I _{load} = 0.1 mA				500	μA
In Shutdown V _{SD} = 0 V	I _{GNDsh}			1.0	μΑ
Output Noise $C_{nr} = 0 \text{ nF}, I_{load} = 500 \text{ mA}, f = 10 \text{ Hz to } 100 \text{ kHz}, C_{out} = 10 \mu\text{F}$ $C_{nr} = 10 \text{ nF}, I_{load} = 500 \text{ mA}, f = 10 \text{ Hz to } 100 \text{ kHz}, C_{out} = 10 \mu\text{F}$	V _{noise}		56 35		μVrms μVrms
Power Good Voltage Low Threshold Hysteresis High Threshold	V _{elft}	93	95 2 97	99	% of V _{out}
Power Good Pin Voltage Saturation (I _{ef} – 1.0 mA)	V _{efdo}		200		mV
Power Good Pin Leakage	I _{efleak}		1.0		μA
Power Good Blanking Time (Note 7)	t _{ef}		50		μs
Shutdown Threshold Voltage ON Threshold Voltage OFF	V _{SD}	2.0		0.4	V V
S_D Input Current, V_{SD} = 0 V to 0.4 V or V_{SD} = 2.0 V to V_{in}	I _{SD}		0.07	1.0	μΑ
Output Current In Shutdown Mode, V _{out} = 0 V	I _{OSD}		0.07	1.0	μΑ
Reverse Bias Protection, Current Flowing from the Output Pin to GND (V _{in} = 0 V, V _{out_forced} = 2.5 V)	I _{OUTR}		10		μΑ

5. Performance guaranteed over the operating temperature range by design and/or characterization, production tested at T_J = T_A = 25°C. Low duty cycle pulse techniques are used during testing to maintain the junction temperature as close to ambient as possible.
6. T_A must be greater than 0°C.
7. Can be disabled per customer request.

ELECTRICAL CHARACTERISTICS - 3.3 V

(V_{out} = 3.3 V typical, V_{in} = 3.7 V, T_A = -40°C to +125°C, unless otherwise noted, Note 8)

Characteristic	Symbol	Min	Тур	Max	Unit
Output Voltage (Accuracy) V _{in} V _{in} = 3.7 V to 7.3 V, I _{load} = 0.1 mA to 500 mA, T _A = 25°C	V _{out}	-0.90% 3.27	3.3	0.90% 3.33	V
Output Voltage (Accuracy) V_{in} = 3.7 V to 7.3 V, I_{load} = 0.1 mA to 500 mA, T_A = 0°C to +85°C	V _{out}	-1.40% 3.254	3.3	1.40% 3.346	V
Output Voltage (Accuracy) V_{in} = 3.7 V to 7.3 V, I _{load} = 0.1 mA to 500 mA, T _A = -40°C to +125°C	V _{out}	-1.50% 3.25	3.3	1.50% 3.35	V
Line Regulation $V_{in} = 3.7 \text{ V to } 12 \text{ V}, \text{ I}_{load} = 0.1 \text{ mA}$	Line _{Reg}		0.04		mV/V
Load Regulation $V_{in} = 3.7 \text{ V}, \text{ I}_{load} = 0.1 \text{ mA to } 500 \text{ mA}$	Load _{Reg}		0.04		mV/mA
Dropout Voltage $I_{load} = 500 \text{ mA}$ $I_{load} = 300 \text{ mA}$ $I_{load} = 50 \text{ mA}$ $I_{load} = 0.1 \text{ mA}$	V _{DO}		340 230 110 10		mV
Peak Output Current (See Figure 14)	I _{pk}	500	700	800	mA
Short Output Current (See Figure 14) V_{in} < 7 V, T_A = 25°C	I _{sc}			900	mA
Thermal Shutdown / Hysteresis	ТJ		160/10		°C
Ground Current In Regulation $I_{load} = 500 \text{ mA}$ (Note 8) $I_{load} = 300 \text{ mA}$ $I_{load} = 50 \text{ mA}$ $I_{load} = 0.1 \text{ mA}$ In Dropout $V_{in} = 3.7 \text{ V}, I_{load} = 0.1 \text{ mA}$	I _{GND}		9 4.6 0.8 -	14 7.5 2.5 220 500	mA μA μA
In Shutdown $V_{SD} = 0 V$	I _{GNDsh}			1	μA
Output Noise $C_{nr} = 0 \text{ nF}, \text{ I}_{load} = 500 \text{ mA}, \text{ f} = 10 \text{ Hz to } 100 \text{ kHz}, C_{out} = 10 \mu\text{F}$ $C_{nr} = 10 \text{ nF}, \text{ I}_{load} = 500 \text{ mA}, \text{ f} = 10 \text{ Hz to } 100 \text{ kHz}, C_{out} = 10 \mu\text{F}$	V _{noise}		69 46		μVrms
Power Good Voltage Low Threshold Hysteresis High Threshold	V _{elft}	93	95 2 97	99	% of V _{out}
Power Good Pin Voltage Saturation (I _{ef} = 1.0 mA)	V _{efdo}		200		mV
Power Good Pin Leakage	I _{efleak}		1		μΑ
Power Good Blanking Time (Note 9)	t _{ef}		50		μs
Shutdown Threshold Voltage ON Threshold Voltage OFF	V _{SD}	2		0.4	V
SD Input Current, V_{SD} = 0 V to 0.4 V or V_{SD} = 2.0 V to V_{in}	I _{SD}		0.07	1	μA
Output Current In Shutdown Mode, V _{out} = 0 V	I _{OSD}		0.07	1	μA
Reverse Bias Protection, Current Flowing from the Output Pin to GND (V _{in} = 0 V, V _{out forced} = 3.3 V)	I _{OUTR}		10		μA

Performance guaranteed over the operating temperature range by design and/or characterization, production tested at T_J = T_A = 25°C. Low duty cycle pulse techniques are used during testing to maintain the junction temperature as close to ambient as possible.
Can be disabled per customer request.

ELECTRICAL CHARACTERISTICS - 5 V

(V_{out} = 5.0 V typical, V_{in} = 5.4 V, T_A = -40°C to +125°C, unless otherwise noted, Note 10)

Characteristic	Symbol	Min	Тур	Max	Unit
Output Voltage (Accuracy) V_{in} V_{in} = 5.4 V to 7.3 V, I_{load} = 0.1 mA to 500 mA, T_A = 25°C	V _{out}	-0.90% 4.955	5	0.90% 5.045	V
Output Voltage (Accuracy) V_{in} = 5.4 V to 7.3 V, I_{load} = 0.1 mA to 500 mA, T_A = 0°C to +85°C	V _{out}	-1.40% 4.93	5	1.40% 5.07	V
Output Voltage (Accuracy) V_{in} = 5.4 V to 7.3 V, I _{load} = 0.1 mA to 500 mA, T _A = -40°C to +125°C	V _{out}	-1.50% 4.925	5	1.50% 5.075	V
Line Regulation $V_{in} = 5.4 \text{ V to } 12 \text{ V}, \text{ I}_{load} = 0.1 \text{ mA}$	Line _{Reg}		0.04		mV/V
Load Regulation $V_{in} = 5.4 \text{ V}, \text{ I}_{load} = 0.1 \text{ mA to } 500 \text{ mA}$	Load _{Reg}		0.04		mV/mA
Dropout Voltage $I_{load} = 500 \text{ mA}$ $I_{load} = 300 \text{ mA}$ $I_{load} = 50 \text{ mA}$ $I_{load} = 0.1 \text{ mA}$	V _{DO}			340 230 110 10	mV
Peak Output Current (See Figure 14)	I _{pk}	500	700	830	mA
Short Output Current (See Figure 14) V_{in} < 7 V, T_A = 25°C	I _{sc}			930	mA
Thermal Shutdown / Hysteresis	TJ		160/10		°C
Ground Current In Regulation $I_{load} = 500 \text{ mA} \text{ (Note 10)}$ $I_{load} = 300 \text{ mA}$ $I_{load} = 50 \text{ mA}$ $I_{load} = 0.1 \text{ mA}$ In Dropout $V_{in} = 3.2 \text{ V}, I_{load} = 0.1 \text{ mA}$	IGND		9 4.6 0.8 -	14 7.5 2.5 220 500	mA μA μA
In Shutdown V _{SD} = 0 V	I _{GNDsh}			1	μA
Output Noise $C_{nr} = 0 \text{ nF}, \text{ I}_{load} = 500 \text{ mA}, \text{ f} = 10 \text{ Hz to } 100 \text{ kHz}, C_{out} = 10 \mu\text{F}$ $C_{nr} = 10 \text{ nF}, \text{ I}_{load} = 500 \text{ mA}, \text{ f} = 10 \text{ Hz to } 100 \text{ kHz}, C_{out} = 10 \mu\text{F}$	V _{noise}		93 58		μVrms
Power Good Voltage Low Threshold Hysteresis High Threshold	V _{elft}	93	95 2 97	99	% of V _{out}
Power Good Pin Voltage Saturation (I _{ef} = 1.0 mA)	V _{efdo}		200		mV
Power Good Pin Leakage	I _{efleak}		1		μΑ
Power Good Blanking Time (Note 11)	t _{ef}		50		μs
Shutdown Threshold Voltage ON Threshold Voltage OFF	V _{SD}	2		0.4	V
SD Input Current, V_{SD} = 0 V to 0.4 V or V_{SD} = 2.0 V to V_{in}	I _{SD}		0.07	1	μΑ
Output Current In Shutdown Mode, V _{out} = 0 V	I _{OSD}		0.07	1	μΑ
Reverse Bias Protection, Current Flowing from the Output Pin to GND (V _{in} = 0 V, V _{out_forced} = 5 V)	I _{OUTR}		10		μΑ

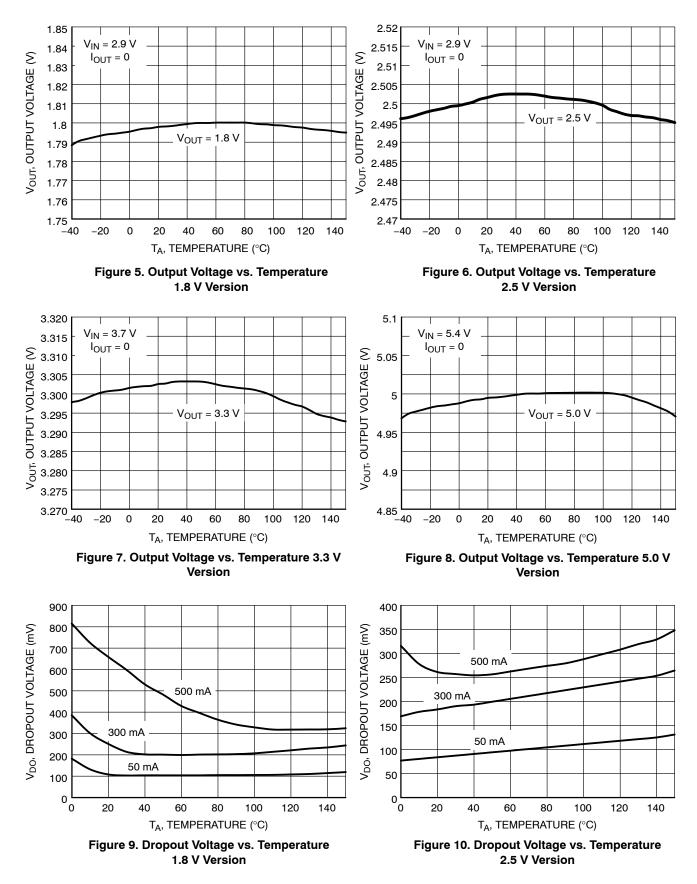
Performance guaranteed over the operating temperature range by design and/or characterization, production tested at T_J = T_A = 25°C. Low duty cycle pulse techniques are used during testing to maintain the junction temperature as close to ambient as possible.
Can be disabled per customer request.

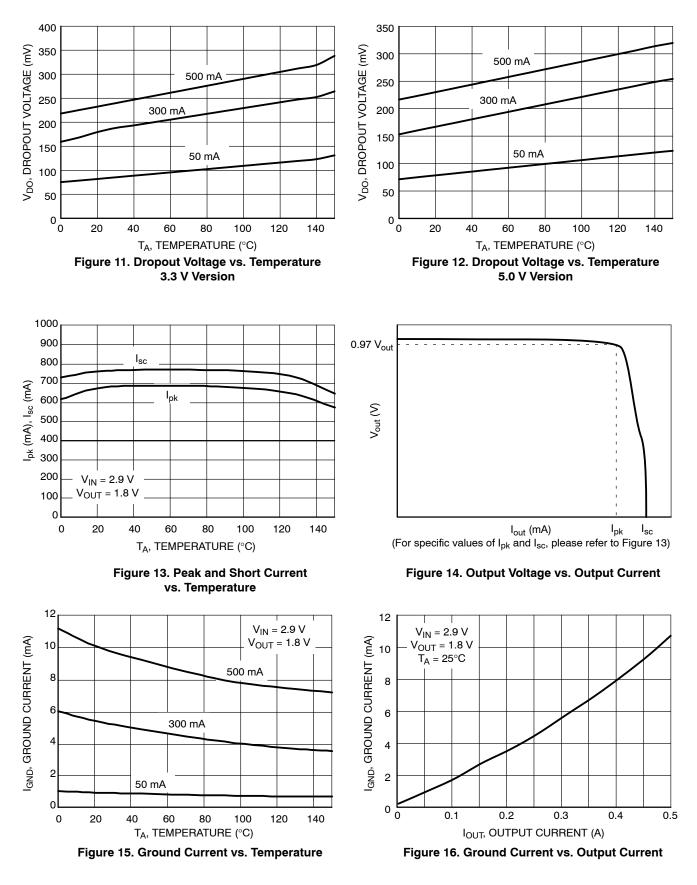
ELECTRICAL CHARACTERISTICS - ADJUSTABLE

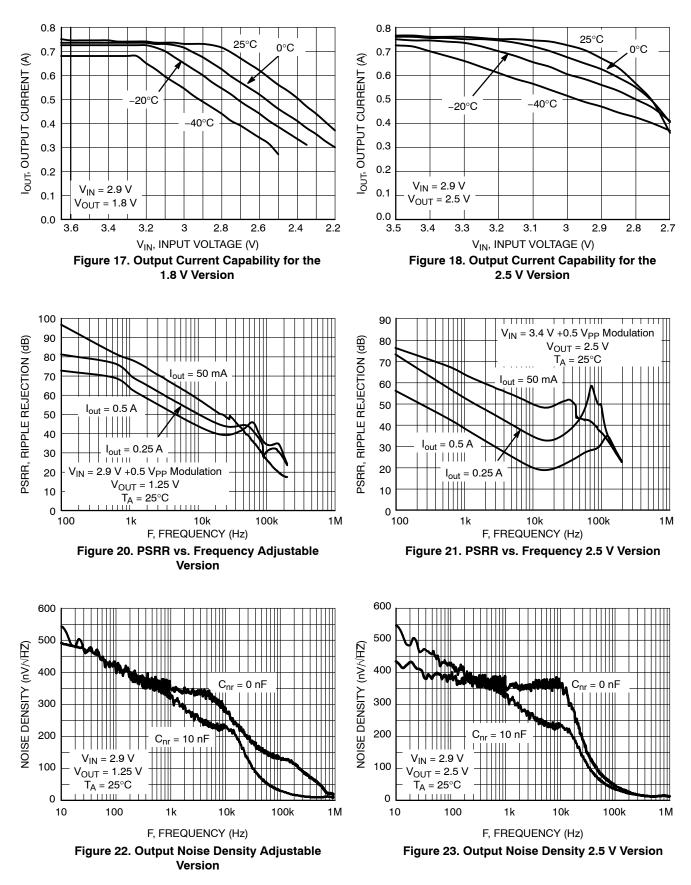
(V_{out} = 1.25 V typical, V_{in} = 2.9 V, T_A = -40° C to $+125^{\circ}$ C, unless otherwise noted, Note 12)

Characteristic	Symbol	Min	Тур	Max	Unit
Reference Voltage (Accuracy) V_{in} = 2.9 V to V _{out} +4.0 V, I _{load} = 0.1 mA to 500 mA, T _A = 25°C	V _{ref}	-0.90% 1.239	1.25	0.90% 1.261	V
Reference Voltage (Accuracy) V_{in} = 2.9 V to V_{out} + 4.0 V, I_{load} = 0.1 mA to 500 mA, T_A = 0°C to +85°C	V _{ref}	-1.40% 1.233	1.25	1.40% 1.268	V
Reference Voltage (Accuracy) V_{in} = 2.9 V to V_{out} + 4.0 V, I_{load} = 0.1 mA to 500 mA, T_A = -40°C to +125°C	V _{ref}	-1.50% 1.231	1.25	1.50% 1.269	V
Line Regulation $V_{in} = 2.9 \text{ V}$ to 12 V, $I_{load} = 0.1 \text{ mA}$	Line _{Reg}		0.04		mV/V
Load Regulation $V_{in} = 2.9$ V to 12 V, $I_{load} = 0.1$ mA to 500 mA	Load _{Reg}		0.04		mV/mA
Dropout Voltage ($V_{out} = 2.5 \text{ V} - 10 \text{ V}$) $I_{load} = 500 \text{ mA}$ $I_{load} = 300 \text{ mA}$ $I_{load} = 50 \text{ mA}$ $I_{load} = 0.1 \text{ mA}$	V _{DO}		340 230 110 10		mV
Peak Output Current (See Figure 14)	I _{pk}	500	700	830	mA
Short Output Current (See Figure 14) V_{in} < 7 V, T_A = 25°C V_{out} \leq 3.3 V V_{out} > 3.3 V	I _{sc}			900 930	mA
Thermal Shutdown / Hysteresis	TJ		160/ 10		°C
Ground Current In Regulation $I_{load} = 500 \text{ mA} \text{ (Note 12)}$ $I_{load} = 300 \text{ mA}$ $I_{load} = 50 \text{ mA}$ $I_{load} = 0.1 \text{ mA}$ In Dropout Vin = V _{out} + 0.1 V or 2.9 V (whichever is higher), $I_{load} = 0.1 \text{ mA}$ In Shutdown $V_{SD} = 0 \text{ V}$	I _{GND}		9 4.6 0.8	14 7.5 2.5 220 500	mΑ μΑ μΑ μΑ
Output Noise C _{nr} = 0 nF, I _{load} = 500 mA, f = 10 Hz to 100 kHz, Cout = 10 μF C _{nr} = 10 nF, I _{load} = 500 mA, f = 10 Hz to 100 kHz, Cout = 10 μF	V _{noise}		69 46		μV _{rms}
Power Good Voltage Low Threshold Hysteresis High Threshold	V _{elft}	93	95 2 97	99	% of V _{out}
Power Good Pin Voltage Saturation (I _{ef} = 1.0 mA)	V _{efdo}		200		mV
Power Good Pin Leakage	I _{efleak}		1		μA
Power Good Pin Blanking Time (Note 13)	t _{ef}		50		μs
Shutdown Threshold Voltage ON Threshold Voltage OFF	V _{SD}	2		0.4	V
SD Input Current, V_{SD} = 0 V to 0.4 V or V_{SD} = 2.0 V to V_{in} V_{in} \leq 5.4 V V_{in} $>$ 5.4 V	I _{SD}		0.07	1 5	μΑ
Output Current In Shutdown Mode, Vout = 0 V	I _{OSD}		0.07	1	μA
Reverse Bias Protection, Current Flowing from the Output Pin to GND (V _{in} = 0 V, V _{out forced} = V _{out (nom)} ≤ 7 V)	IOUTR		1		μΑ

Performance guaranteed over the operating temperature range by design and/or characterization, production tested at T_J = T_A = 25°C. Low duty cycle pulse techniques are used during testing to maintain the junction temperature as close to ambient as possible.
Can be disabled per customer request.







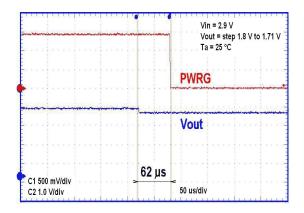


Figure 24. Power Good Activation

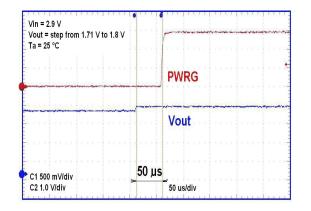
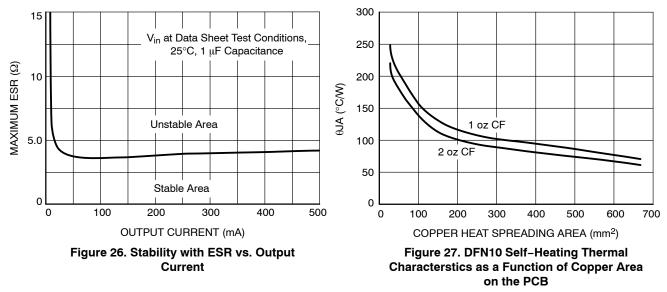


Figure 25. Power Good Inactivation



NOTE: Typical characteristics were measured with the same conditions as electrical characteristics.

APPLICATIONS INFORMATION

Reverse Bias Protection

Reverse bias is a condition caused when the input voltage goes to zero, but the output voltage is kept high either by a large output capacitor or another source in the application which feeds the output pin.

Normally in a bipolar LDO all the current will flow from the output pin to input pin through the PN junction with limited current capability and with the potential to destroy the IC.

Due to an improved architecture, the NCV8537 can withstand up to 7.0 V on the output pin with virtually no current flowing from output pin to input pin, and only negligible amount of current (tens of μ A) flowing from the output pin to ground for infinite duration.

Input Capacitor

An input capacitor of at least 1.0 μ F, any type, is recommended to improve the transient response of the regulator and/or if the regulator is located more than a few inches from the power source. It will also reduce the circuit's sensitivity to the input line impedance at high frequencies. The capacitor should be mounted with the shortest possible track length directly across the regular's input terminals.

Output Capacitor

The NCV8537 remains stable with any type of capacitor as long as it fulfills its 1.0 μ F requirement. There are no constraints on the minimum ESR and it will remain stable up to an ESR of 5.0 Ω . Larger capacitor values will improve the noise rejection and load transient response.

Noise Reduction Pin

Output noise can be greatly reduced by connecting a 10 nF capacitor (C_{nr}) between the noise reduction pin and ground (see Figure 1). In applications where very low noise is not required, the noise reduction pin can be left unconnected.

Dropout Voltage

The voltage dropout is measured at 97% of the nominal output voltage.

Thermal Considerations

Internal thermal limiting circuitry is provided to protect the integrated circuit in the event that the maximum junction temperature is exceeded. This feature provides protection from a catastrophic device failure due to accidental overheating. This protection feature is not intended to be used as a substitute to heat sinking. The maximum power that can be dissipated, can be calculated with the equation below:

$$P_{D} = \frac{T_{J}(max) - T_{A}}{R_{\theta}JA} \qquad (eq. 1)$$

For improved thermal performance, contact the factory for the DFN package option. The DFN package includes an exposed metal pad that is specifically designed to reduce the junction to air thermal resistance, $R_{\rm BJA}$.

Adjustable Operation

The output voltage can be set by using a resistor divider as shown in Figure 2 with a range of 1.25 to 10 V. The appropriate resistor divider can be found by solving the equation below. The recommended current through the resistor divider is from 10 μ A to 100 μ A. This can be accomplished by selecting resistors in the k Ω range. As result, the I_{adj} * R2 becomes negligible in the equation and can be ignored.

$$V_{out} = 1.25 * (1 + R3/R2) + I_{adi} * R2$$
 (eq. 2)

Power Good Operation

The Power Good pin on the NCV8537 will produce a logic Low when it drops below the nominal output voltage. Refer to the electrical characteristics for the threshold values at which point the Power Good goes Low. When the NCV8537 is above the nominal output voltage, the Power Good will remain at logic High.

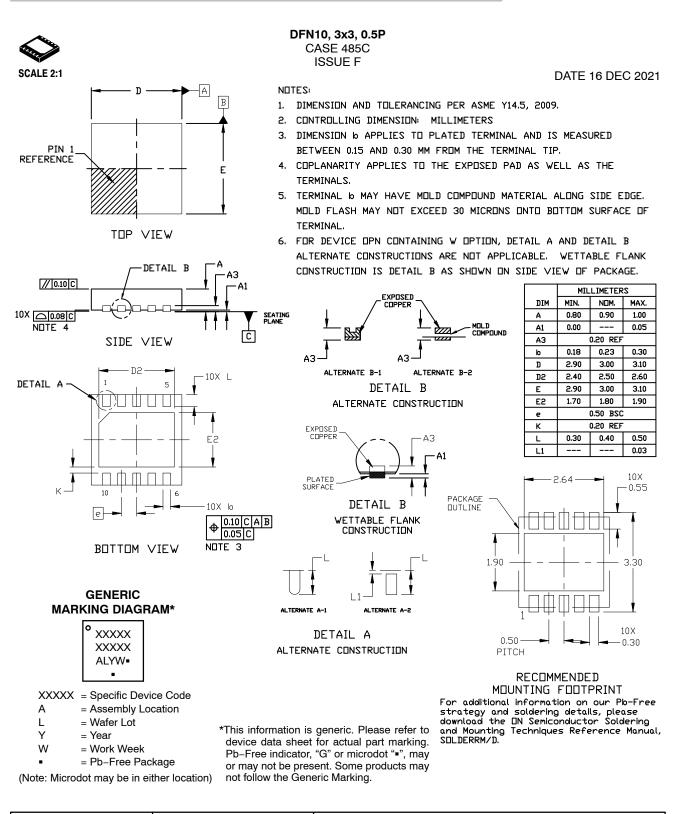
The external pullup resistor needs to be connected between V_{in} and the Power Good pin. A resistor of approximately 100 k Ω is recommended to minimize the current consumption. No pullup resistor is required if the Power Good output is not being used. The Power Good does not function during thermal shutdown and when the part is disabled.

ORDERING INFORMATION

Device*	Voltage Option	Marking	Package	Package	Shipping [†]	
NCV8537MN180R2G	1.8 V	V8537 180	DFN10 (Pb-Free)	Non-Wettable Flank		
NCV8537MN250R2G	2.5 V	V8537 250				
NCV8537MN330R2G	3.3 V	V8537 330			3000 / Tape & Reel	
NCV8537MN500R2G	5.0 V	V8537 500	(. 2			
NCV8537MNADJR2G	Adj	V8537 ADJ				
NCV8537ML180R2G	1.8 V	L8537 180				
NCV8537ML250R2G	2.5 V	L8537 250				
NCV8537ML330R2G	3.3 V	L8537 330	DFN10 (Pb–Free)	Wettable Flank SLP Process	3000 / Tape & Reel	
NCV8537ML500R2G	5.0 V	L8537 500	(
NCV8537MLADJR2G	Adj	L8537 ADJ	1			

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.
*NCV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q100 Qualified and PPAP

Capable.



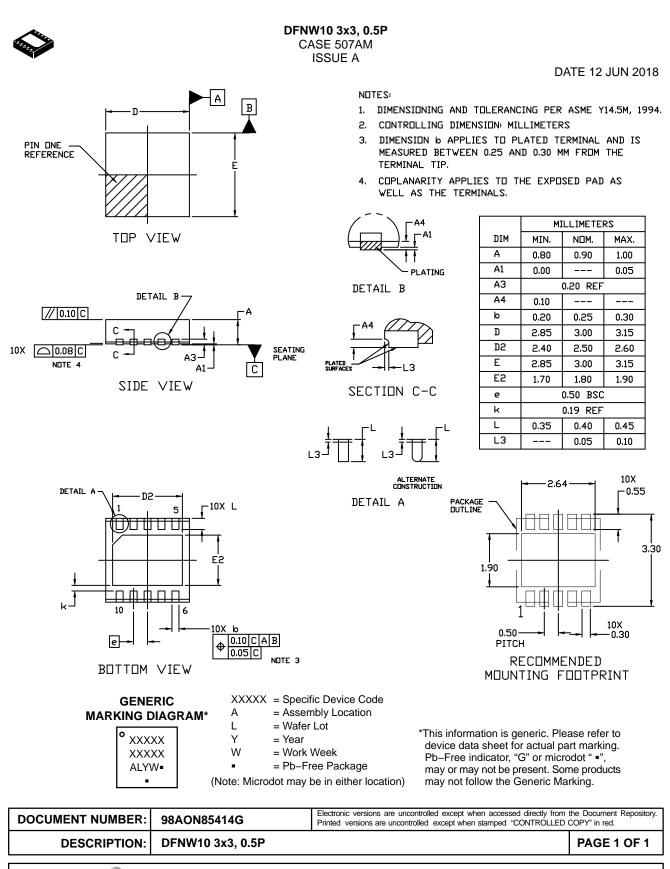
DOCUMENT NUMBER:	98AON03161D	Electronic versions are uncontrolled except when accessed directly from the Document I Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.				
DESCRIPTION: DFN10, 3X3 MM, 0.5 MM PITCH						
onsemi and ONSEMI. are trademarks of Semiconductor Components Industries, LLC dba onsemi or its subsidiaries in the United States and/or other countries. onsemi reserves the right to make changes without further notice to any products herein. onsemi makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation						

special, consequential or incidental damages. onsemi does not convey any license under its patent rights nor the rights of others.

© Semiconductor Components Industries, LLC, 2019

DUSEM





ON Semiconductor and ()) are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the rights of others.

onsemi, ONSEMI, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. onsemi reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does **onsemi** assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using **onsemi** products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by **onsemi**. "Typical" parameters which may be provided in **onsemi** data sheets and/or specifications can and do vary in different applications and calcular performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. **onsemi** does not convey any license under any of its intellectual property rights nor the rights of others. **onsemi** products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use **onsemi** products for any such unintended or unauthorized application, Buyer shall indemnify and hold **onsemi** and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that **onsemi** was negligent regarding the design or manufacture of the part. **onsemi** is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

TECHNICAL SUPPORT

onsemi Website: www.onsemi.com

Email Requests to: orderlit@onsemi.com

North American Technical Support: Voice Mail: 1 800-282-9855 Toll Free USA/Canada Phone: 011 421 33 790 2910

Europe, Middle East and Africa Technical Support: Phone: 00421 33 790 2910 For additional information, please contact your local Sales Representative

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for LDO Voltage Regulators category:

Click to view products by ON Semiconductor manufacturer:

Other Similar products are found below :

AP7363-SP-13 L79M05TL-E PT7M8202B12TA5EX TCR3DF185,LM(CT TCR3DF24,LM(CT TCR3DF285,LM(CT TCR3DF31,LM(CT TCR3DF31,LM(CT TCR3DF45,LM(CT MP2013GQ-33-Z 059985X NCP4687DH15T1G 701326R TCR2EN28,LF(S NCV8170AXV250T2G TCR3DF27,LM(CT TCR3DF19,LM(CT TCR3DF125,LM(CT TCR2EN18,LF(S AP2112R5A-3.3TRG1 AP7315-25W5-7 IFX30081LDVGRNXUMA1 NCV47411PAAJR2G AP2113KTR-G1 AP2111H-1.2TRG1 ZLD01117QK50TC AZ1117IH-1.8TRG1 AZ1117ID-ADJTRG1 TCR3DG12,LF MIC5514-3.3YMT-T5 MIC5512-1.2YMT-T5 MIC5317-2.8YM5-T5 SCD7912BTG NCP154MX180270TAG SCD33269T-5.0G NCV8170BMX330TCG NCV8170AMX120TCG NCP706ABMX300TAG NCP153MX330180TCG NCP114BMX075TCG MC33269T-3.5G CAT6243-ADJCMT5T TCR3DG33,LF AP2127N-1.0TRG1 TCR4DG35,LF LT1117CST-3.3 LT1117CST-5 TAR5S15U(TE85L,F) TAR5S18U(TE85L,F) TCR3UG19A,LF TCR4DG105,LF